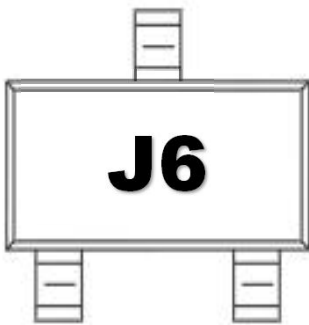


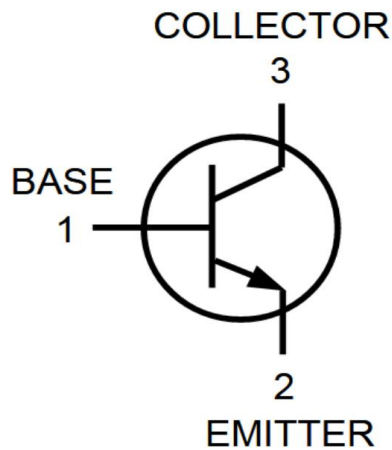
S9014

TRANSISTOR (NPN)

MARKING:

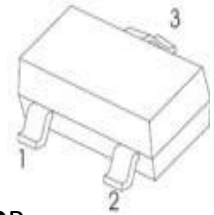


Equivalent Circuit:



SOT-23

- 1.BASE
- 2.EMITTER
- 3.COLLECTOR



FEATURES:

- ※ Complimentary to S9015
- ※ Collector Current: $I_c=100\text{mA}$

MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

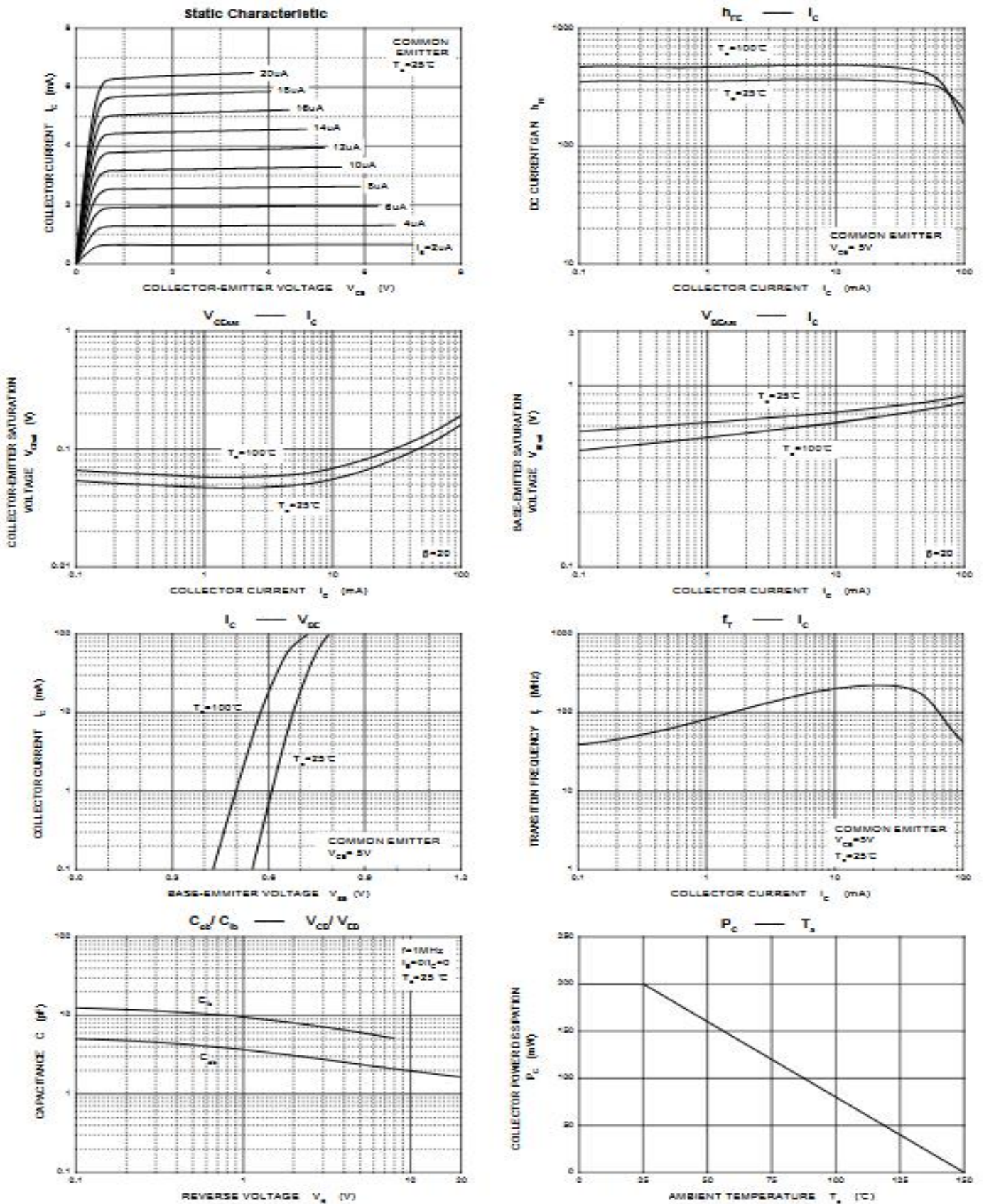
Parameter	Symbol	Value	Unit
Collector-Base Voltage	VCBO	50	V
Collector-Emitter Voltage	VCEO	45	V
Emitter-Base Voltage	VEBO	5	V
Collector Current	IC	100	mA
Collector Power Dissipation	PC	200	mW
Thermal Resistance From Junction To Ambient	ROJA	625	$^\circ\text{C}/\text{W}$
Junction Temperature	Tj	150	$^\circ\text{C}$
Storage Temperature	Tstg	-55~+150	$^\circ\text{C}$

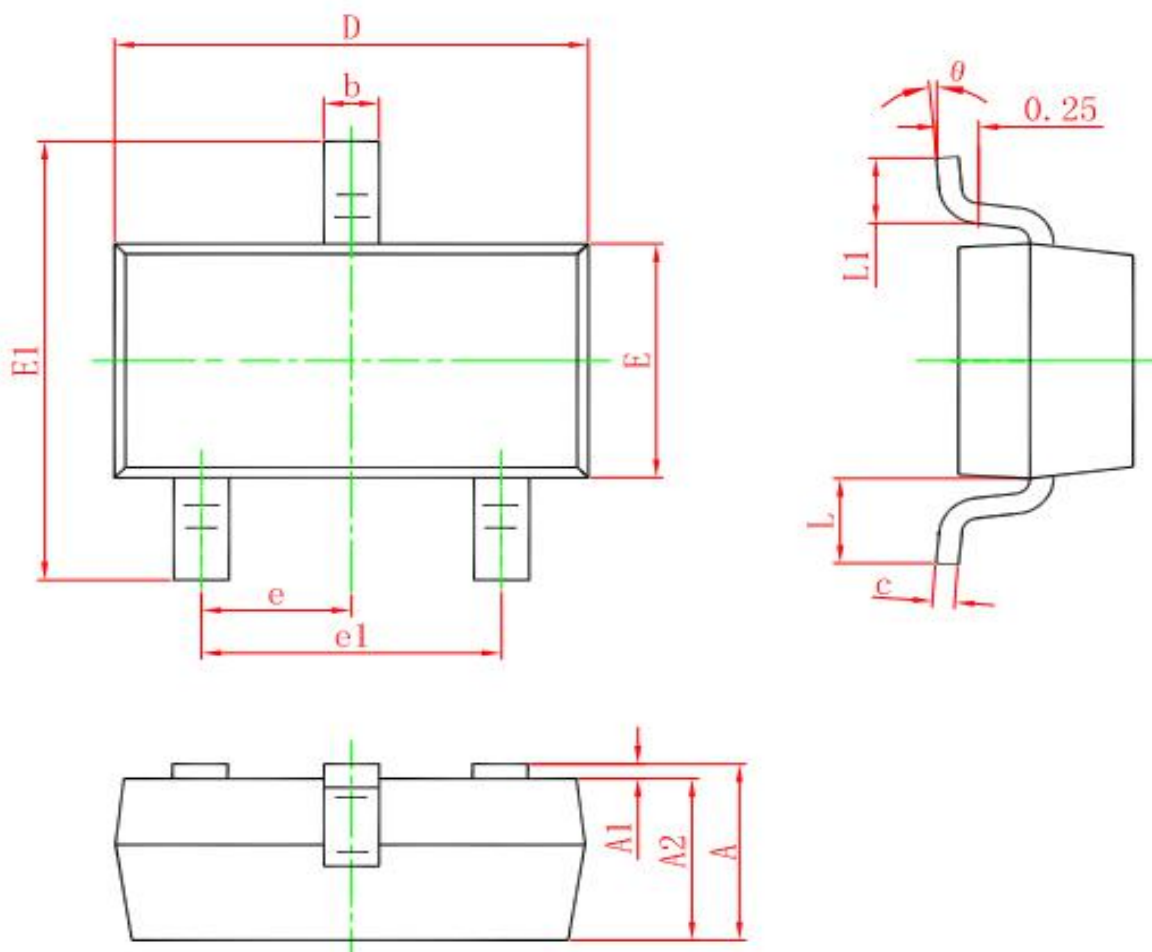
ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Collector-base breakdown voltage	V(BR)CBO	IC= 100μA, IE=0	50			V
Collector-emitter breakdown voltage	V(BR)CEO	IC= 0.1mA, IB=0	45			V
Emitter-base breakdown voltage	V(BR)EBO	IE= 100μA, IC=0	5			V
Collector cut-off current	ICBO	VCB= 50 V , IE=0			0.1	μA
Collector cut-off current	ICEO	VCB= 35V , IE=0			1	μA
Emitter cut-off current	IEBO	VEB= 6V , IC=0			0.1	μA
DC current gain	hFE	VCE=5V, IC= 1mA	300		400	
Collector-emitter saturation voltage	VCE(sat)	IC=100 mA, IB= 5mA			0.3	V
Base-emitter saturation voltage	VBE(sat)	IC=100 mA, IB= 5mA			1	V
Transition frequency	fT	VCE=6V, IC= 20mA f=30MHz	150			MHz

CLASSIFICATION OF hFE

Range	300-400
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TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS


SOT-23 PACKAGE OUTLINE DIMENSIONS


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°